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3.2x1.6mm SMD CHIP LED LAMP

KPTD-3216SYC SUPER BRIGHT YELLOW

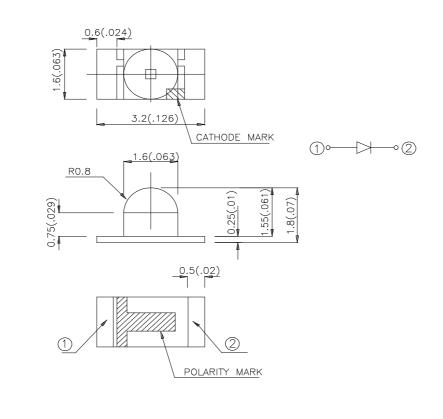
Features

•3.2mmx1.6mm SMT LED,1.8mm THICKNESS. •LOW POWER CONSUMPTION. •WIDE VIEWING ANGLE. •IDEAL FOR BACKLIGHT AND INDICATOR. •PACKAGE : 2000PCS / REEL. •RoHS COMPLIANT.

Description

The Super Bright Yellow device is made with DH InGaAIP (on GaAs substrate) light emitting diode chip.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches). 2. Tolerance is $\pm 0.2(0.0079")$ unless otherwise noted.

3. Specifications are subject to change without notice.

SPEC NO: DSAB9154 APPROVED: J. Lu

REV NO: V.7 CHECKED: Allen Liu DATE: MAR/14/2005 DRAWN: W.J.ZHU

Selection Guide								
Part No.	Dice	Lens Type	lv (mcd) @ 20mA		Viewing Angle			
			Min.	Тур.	2 0 1/2			
KPTD-3216SYC	SUPER BRIGHT YELLOW (InGaAIP)	WATER CLEAR	110	300	50 °			

Note: 1. θ 1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

Electrical / Optical Characteristics at TA=25°C

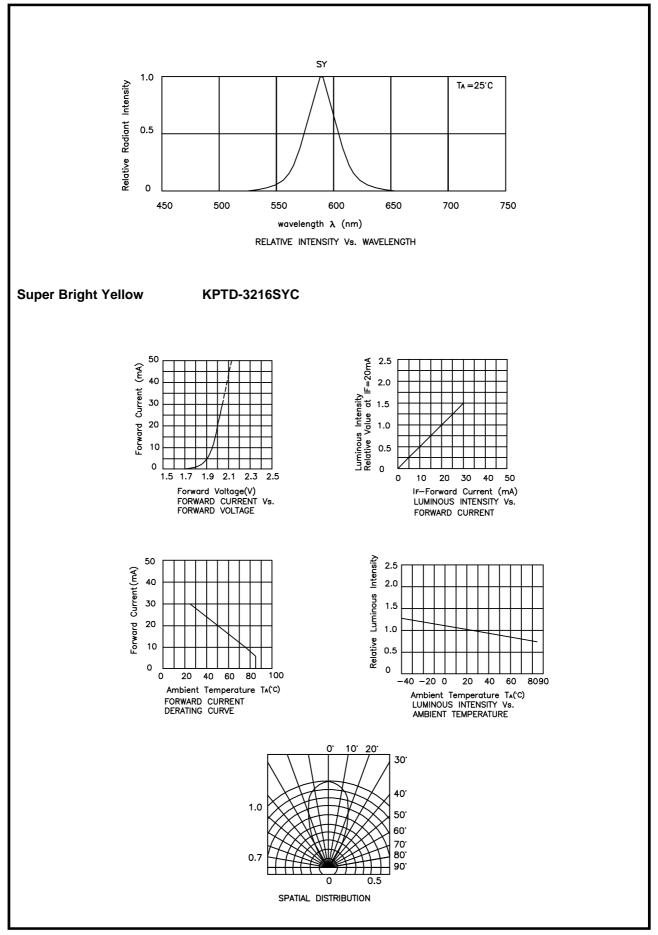
Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Yellow	590		nm	IF=20mA
λD	Dominant Wavelength	Super Bright Yellow	588		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	Super Bright Yellow	28		nm	IF=20mA
С	Capacitance	Super Bright Yellow	25		pF	VF=0V;f=1MHz
VF	Forward Voltage	Super Bright Yellow	2.0	2.5	V	IF=20mA
lr	Reverse Current	Super Bright Yellow		10	uA	Vr = 5V

Absolute Maximum Ratings at TA=25°C

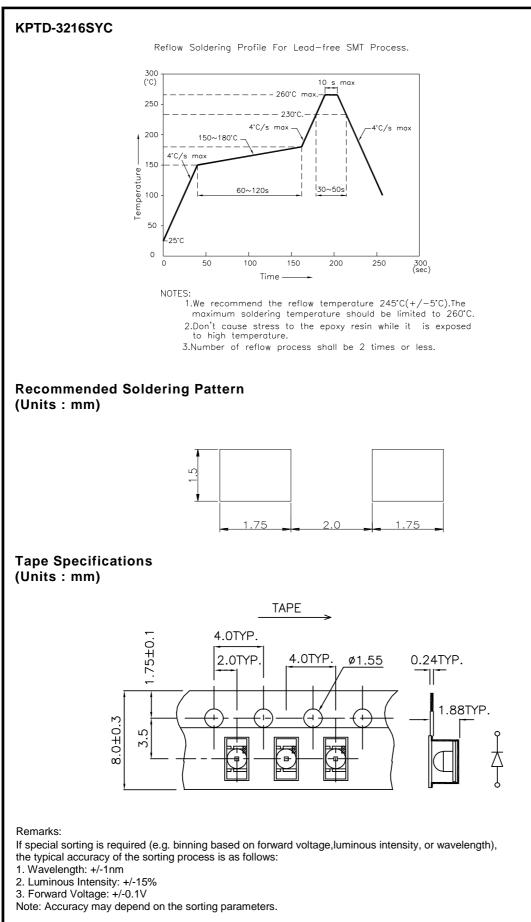
Parameter	Super Bright Yellow	Units
Power dissipation	125	mW
DC Forward Current	30	mA
Peak Forward Current [1]	150	mA
Reverse Voltage	5	V
Operating/Storage Temperature -40°CTo +85°C		

Note:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.



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